E-Beam Lithography Mastering Microscopy Calibration Standards

APPLICATIONS

Application areas

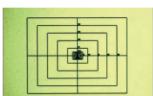
- ✓ Calibration standards suitable for large range of optical instruments, microscopes particularly.
- ✓ List of imaging systems optical imaging (camera, loupe); light microscopy (transmitted, reflected); confocal laser scanning microscopy (CLSM); electron—beam microscopy (scanning, transmission); step height measurements (profilometer; scanning—probe and atomic—force microscopy — SPM, AFM).

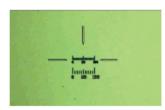
Calibration tasks

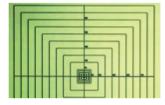
- ✓ Samples, chips and slides check and calibration of optical device parameters (dimension, orthogonality, linearity..).
- ✓ Interferometry e-beam patterning system assures testing pattern precision.
- ✓ Precise step height for profilometer and SPM/AFM.
- ✓ Combining several metals (SEM material contrast imaging)

CASE STUDY — PATTERN EXAMPLES



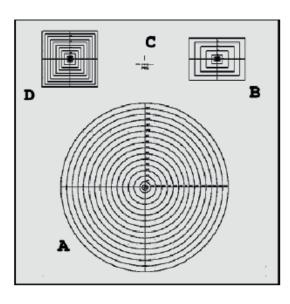






Selected calibration patterns for reflected–light microscopy

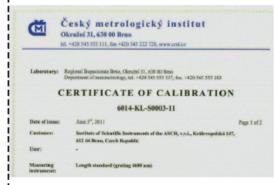
- ✓ Concentric circles
- ✓ Concentric rectangles
- ✓ Micro scale
- ✓ Concentric squares





Institute of Scientific Instruments of the CAS, v.v.i.
The Czech Academy of Sciences

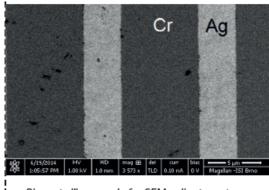
Královopolská 147, 612 64 Brno, The Czech Republic www.isibrno.cz http://ebl.isibrno.cz/



Certificate of Calibration issued by the Czech Institute of Metrology

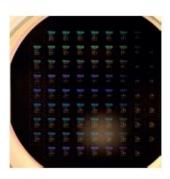


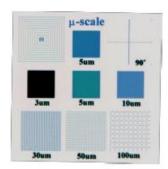
Various-purpose calibration chips

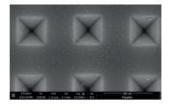


Bi-metallic sample for SEM adjustment

ANISOTROPICALY ETCHED SILICON FEATURES







Wafer

- Calibration samples may be designed as a set of samples on single Si wafer (e.g. 77 items on the 4" wafer).
- Individual items may be identical, personalized or different.

Chip layout

- One chip is composed of several selected patterns.
- Usual patterns include grating of selected density, concentric squares or orthogonal lines.

Notches

 Patterns composed of extremely sharp etched edges are optimal for SEM check and calibration.



WHAT YOU WILL BENEFIT FROM

- ✓ More than 20 years of design experience.
- ✓ Optional Authority Certificate of Calibration.
- ✓ From science through R&D, to final product.



Origination system e–beam pattern generator

Technical Advantages

- ✓ High flexibility in design (combination of various features).
- ✓ Specific substrate shape and/ or size available.
- ✓ Large selection of protection-layer coating.
- ✓ Customer–related approach.

1951 USAF resolution test chart; range of group numbers: 0 – 11; sample size 25 mm x 75 mm

